Transistors ____

SST (U. S. /European SOT-23) · SMT (SC-59/Japanese SOT-23)

ONPN Transistors

General purpose small signal amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Mín.	BV _{EBO} Min.	I _{CBO} @VCB Max.	h _F Min.	E @lc & Max.	V _{C.E}	V _{CE} (sat) Max.	& V _{BE} (sat) & Max.	@ lc	Cob Max.	f _T Min.	@ lc	NF	lc Max.	DIE NO.	MARKING
SST1130	MMST1130	30V	25V	5V	50nA 20V	120	360 2mA 50mA		0.3V	0.95V	50mA	4pF				200mA	C22	R1C
SST5088	MMST5088	35V	30V	4.5V	100nA 30V	350	900 100 μ A 1.0mA	5V	0. 3V	0.8V	10mA	4pF	50MHz	0.5mA	3dB	200mA	C22	R1Q
SST5089	MMST5089	30V	25V	4.5V	100nA 25V		10mA 1200 0.1mA 1mA 10mA	5 √	0.5V	(V _{BE} (on)) 0.8V (V _{BE} (on))	10mA	4pF	50MHz	0.5mA		200mA	C22	R1R
SST5210	_	50V	50V	4.5V	50nA 35V		600 100 μ A 1.0mA 10mA	٤·٧	0.7V	0.85V (V _{BE (on)})	10mA	4pF	30MHz	0.5mA	2dB	200mA	C22	RSR
SST6428	MMST6428	60V	50V	бV	100nA 30V	250 250 250 250	0.01mA 0.1mA 650 1mA 10mA	€ V	0.2V 0.6V		10mA 100mA	3pF	100MHz	1mA		200mA	C22	R1K
SST6838	MMST6838	50V	40V	5V	0.5 µ A 30V	200 150	1mA 10mA	ŧν	0.4V		50mA	3.5pF	50MHz	2mA		200mA	C22	RBR
SST7208	_	60V	60V	5 V	0.2 μ A 60V (CER)	75 100	10mA 1mA		0.4V	1.2V 1.0V 0.95V	100mA 10mA 1mA		180MHz	Тур.		100mA	C22	RBQ
SSTTIS97	_	60V	40V	6V	50nA 40V	250	700 0.1mA	٠ ٤ ٧	,	0.65V (V _{BE (on)})	0.1mA	4pF			2dB	:200mA	C22	R97
SSTA 20	MMSTA20	40V	40V	5 V	100nA 30V	120	2mA	- v	0.25V	0.95V	10mA	4pF	125MHz	5mA		:200mA	C22	R1C

General purpose amplifiers and switches

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCB Max.	h _{FE} Min. Ma	@lc &	VOE	V _{CE} (sat) Max.	& V _{BE} (sat) Max.) @ lc	Cob Max.	f _T Min,	@ lc	t _{off} Max.	lc Max.	DIE NO.	MARKING
SST2222 SST2222A	MMST2222	60V	30V 40V	5V	100nA 50V	35 50 75 100 300 50 30 35 50 75 100 300	0.1mA 1.0mA 10mA 150mA 150mA 500mA 0.1mA 1.0mA 10mA	10V 10V 10V 10V 10V 10V 10V	0.4V 1.6V	1.3V 2.6V 1.2V 2V	150mA 500mA 150mA	8pF 8pF	250MHz		285ns	600mA	C31	R1B
SST3904	MMST3904	60V	40V	6V	50nA 30V (CEX)	50 30 40 70 100 300 60 30	150mA 500mA 0.1mA 1.0mA 10mA 50mA	10 <u>V</u> ·V ·V ·V	0.2V 0.3V	0.85V 0.95V	10mA 50mA	4pF	300MHz	: 10mA	250ns	200mA	C37	R1A
SST4124	MMST4124	30V	25V	5V	50nA 20V	120 360 60		V	0.3V	0.95V	50mA	4pF	300MHz	: 10mA		200mA	C37	RZC
SST4400	_	60V	40V	6 V	100nA 35V	20 40 50 150 20	1.0mA 10mA 150mA 500mA	·V	0.4V 0.75V	0.95V 1.2V	150mA 500mA	6.5pF	200MHz	20mA	255ns	600mA	C31	R2Z
SST4401	MMST4401	60V	40V	6V	100nA 35V		0.1mA 1mA 10mA 150mA 500mA	∨ ·∨ :∨	0.4V 0.75V	0.95V 1.2V	150mA 500mA	6.5pF	250MHz	: 20mA	225ns	600mA	C31	R2X

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Medium power amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCB Ma x.	h _{FE} Міл. Мах.	@lc &	V _{CE}	V _{CE} (sat) Max.	& V _{BE} (sat) @ lc Max.	Cob Max.	f _T @ lc Min.	t _{off} Max.	lc Max.	ETR NECK N.C.
SSTA05	_	60V	60V	4V	100nA 60V	100 100	10mA 100mA		0.25V	1.2V 100mA (V _{BE} (on))		100MHz 10mA		500mA	Dis Rh
SSTA06	MMSTA06	807	80V	4V	100nA 80V	100 100	10mA 100mA		0.25V	1.2V 100mA (V _{BE} (on))		100MHz 10mA		500mA	D16 R1G

Darlington amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCE Max.	h _{FE} Min, Max.	@lc &	V _{CE}	V _{CE} (sat) & Max.	V _{BE} (sa Max.	t) @ lc	Cob Max.	f _T Min.	@ lc	NF	lc Max.	DIE NO.	MARKING
SST6426	_	40V	40V	12V	50nA 30V	20K 200K 30K 300K 20K 200K	10mA 100mA	5V	1.2V 1.5V	2.0V	5mA 500mA	7pF			10dB	500mA	D25	RX7
SST6427	-	40V	40V	12V	50nA 30V	10K 100K 20K 200K 14K 140K	100mA	5V	1.2V 1.5V	2.0V	50mA 500mA	7pF			10dB	500mA	D25	R1J
SSTA13	MMSTA13	(CES) 30V		10V	100nA 30V	5K 10K	10mA 100mA		l 15V	-	100mA	10pF	125MHz	10mA		500mA	D25	R1M
SSTA14	MMSTA14	(CES) 30V		10V	100nA 30V	10K 20K	10mA 100mA		l 1.5V		100mA	10pF	125MHz	10mA		500mA	D25	R1N
SSTA28	MMSTA28	(CES) 80V		12V	100nA 60V	10K 10K	10mA 100mA		l 1.5V		100mA	8pF	125MHz	10mA		500mA	D69	RAT
SSTA29		(CES) 100V		12V	100nA 80V	10K 10K	10mA 100mA		l 1.2V		10mA	8pF	125MHz	10mA		500mA	D69	RAF

RF/UHF/VHF amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCB Max.	h _{FE} Min. Max.	@k	&	V _{CE}	V _{CE} (sat) & Max.	V _{BE} (sat) Max.) @ lc	Cob Max.	f _T Min.	@ lc	NF	lc Max.	DIE NO.	MARKING
SST1139	MMST1139	30V	25V	3V	100nA 25V	60		↓mA	10V	0.5V		4mA	1pF	850MHz	4mA		30mA	C104	R39
SST5424	MMST5424	30V	20V	3V	100nA 18V (CES)	60 150	2.	-mA	4V	0.4V	1.0V	10mA	1.2pF	600MHz	2.5mA		50mA	C33	R24
SST8245	MMST8245	30V	20V	3V	100nA 18V (CES)	60 150	2.	mΑ	4V	0.4V	1.0V	10mA	1.2pF	600MHz	2.5mA		50mA	C33	R3B
SST918	_	30V	15V	3V	100nA 15V	20		₃mA	1 V	0.4V	1.0V	10mA	1.7pF	600MHz	4mA	6dB	50mA	C33	R3B
SST918S	MMST918S	30V	15V	3V	100nA 15V	75		₃mA	1 V	0.4V	1.0V	10mA	1.7pF	600MHz	4mA		50mA	C33	RVY

(Unit:mm)

Package	SST (U. S. /European SOT-23)	•	SMT (SC-59 / Japanese SOT-23)
D mensions	2.9 ± 0.2 1.9 ± 6.2 0.95 0.95 0.45 ± 0.1 0.45 ± 0.1 0.45 ± 0.1 0.15 $\frac{1}{0.00}$ 0.2Min. 1.4 $\frac{1}{0.00}$	Emitter Base Collector	2.9±0.2 1.9±0.2 0.95 0.95 0.95 0.95 0.15 + 0.1 0.15 + 0.1 0.15 + 0.1 0.15 + 0.1 0.15 + 0.1 0.15 + 0.1 0.15 + 0.1 0.2 0.3 0.4 + 0.1 0.3 0.4 + 0.1 0.3 0.4 + 0.1 0.3 0.4 + 0.1 0.5 0.3 0.4 + 0.1 0.5 0.5 0.5 0.5 0.5 0.5 0.5 0.5
Actual size	-		-
Enlarged (×3.0)			

Transistors _____

SST (U. S. / European SOT-23) · SMT (SC-59/Japanese SOT-23)

●PNP Transistors

General purpose small signal amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCE Max.	h _{Fī} Min. N	E @	lc &	V _{CE}	V _{CE} (sat) Max.	V _{BE} (sat Max.) @ lc	Cob Max.	f _T Min,	@ lc	t _{off} / NF Max.	lc Max.	DIE NO.	MARKING
SST5086	MMST5086	50V	50V	3V	100nA 40V	l	500 10	00 μ A .0mA			_	10mA	6pF	40MHz	0.5mA	NF	200mA	A32	R2P
						150		10mA	5V							3dB			''
SST5087	MMST5087	50V	50V	3\/	100nA 40V	1	800 10 1	00 μ A .0mA		1		10mA	6pF	40MHz	0.5mA	NF 2dB	200mA	A32	R2Q
						250		10mA	5V		_					Zub			<u> </u>
SST5101	MMST5101	60V	40V	6V	100nA 55V	200	400	10mA	5V	0.15V		10mA	8pF	125MHz	2mA		200mA	A32	1T1
SST6839	MMST6839	50V	40V	5V		100 100	1(1mA 00mA		0.5V		100mA	3.5pF	50MHz	2mA		200mA	A32	RFQ
						100		1mA								 			
SST7157	MMST7157	60V	60V	5V	100nA 25V	100		00mA		1 0.25V		100mA					200mA	A32	R2Q
SST8598	MMST8598	60V	60V	5V	100nA 60V	100	300	1mA	ŧν	0.5V		100mA	8pF	150MHz	10mA		200mA	A32	R2K
SSTA70	MMSTA70	60V	60V	5V	100nA 30V	160	400	5mA	100	0.2V		100mA	5pF	125MHz	5mA		200mA	A32	R2C

General purpose amplifiers and switches

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCB Max.	h _i Min.	E Max.	@lc &	VCE	V _{CE} (sat) Max.	V _{BE} (sa & Max.	t) @ lc	Cob Max.	f _T Min.	@ lc	t _{off} Max.	lc Max.	DIE NO.	MARKING
SST2907	MMST2907	60V	40V	5\/	100nA 50V	35 50 75		0.1mA 1.0mA 10mA	10V 10V 10V	0.4V 1.6V	1.3V 2.6V	150mA 500mA	8pF	200MHz	50mA		600mA	A31	R2B
SST2907A	MMST2907A	60V	60V	5V	100nA 50V			0.1mA 1.0mA 10mA	10V 10V 10V 10V	0.4V 1.6V	1.3V 2.6V	150mA 500mA	8pF	200MHz	50mA	180ns	600mA	A31	R2F
SST3906	MMST3906	40V	40V	5V	50nA 30V (CES)	60 80 100 60 30	300	0.1mA 1.0mA 10mA 50mA	~ V	0.25V 0.4V	0.85V 0.95V	10mA 50mA	4.5pF	250MHz	10mA	300ns	200mA	A38	R2A
SST4126	MMST4126	25V	25V	4\/	50nA 20V	120 60	360	2mA 50mA	: V	0.4V	0.95V	50mA	4.5pF	250MHz	10mA		200mA	A38	RVZ
SST4403	MMST4403	40V	40V	5V	100nA 35V		300	0.1mA 1mA 10mA 150mA 500mA	2V	0.4V 0.75V	0.95V 1.3V	150mA 500mA	8.5pF	200MHz	20mA	255ns	600mA	A31	R2T
SSTTIS 93	_	40V	40V	5∨	100nA 20V	100	300	50mA	2V	0.25V		50mA					800mA	A31	R93

Medium power amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min,	I _{CBO} @VCB Max.	h _{FE} Min. Max.	@lc &	V _{i,E}	V _{CE} (sat) Max.	V _{BE} (sat & Max.	t) @ lc	Cob Max.	f _T Min.	@ lc	t _{off} Max.	lc Max,	DIE NO.	MARKING
SSTA55	-	60V	60V		100nA 60V	100	10mA 100mA	· V	0.25V	1.2V	100mA		50MHz	100mA		500mA	B93	R2H
SSTA56	MMSTA56	80V	80V	4٧	100nA 80V	100 100	10mA 100mA	.V	0.25V	1.2V	100mA		50MHz	100mA		500mA	B93	R2G

Darlington amplifiers

SST	SMT	BV _{CBO} Min.	BV _{CEO} Min.	BV _{EBO} Min.	I _{CBO} @VCB Max.	h _{FE} Min. Max.	@lc & \	/ _{CE}	V _{CE} (sat) & Max.	V _{BE} (sat) @ lc Max.	Cob Max.	f _T Min.	@ lc	t _{off} / NF	lc Max.	DIE NO.	MARKING
SSTA63	MMSTA63	30V	30V (CES)		100nA 30V	5K	10mA 100mA	5V 5V	1.5V	100mA	7pF	125MHz	10mA	3dB	300mA	B25	R2U
			307			10K	10mA	-∍v -∍V									
SSTA64	MMSTA64	30V	(CES)	10V	100nA 30V	20K	100mA	δV	1.5V	100mA	7pF	125MHz	10mA	3dB	300mA	B25	R2V
SSTA 65	_	30V	(CES)	8٧	100nA 30V	50K	10mA	5 V	1.5V	100mA		100MHz	10mA	2dB	300mA	B25	R65
			30V			20K	100mA	į۷					,,,,,,,			020	1100

SST (U.S. / European SOT-23)

Function	Part No.	Polarity	BV _{CEO} (V)	lc (mA)	h _{FE}	@Condition	f _T (MHz)	Cob (pF)	3.38.71
	BC817-16	NPN	45	800	110~250	100mA / 1V	150	6	3.
	BC817-25	NPN	45	800	160~400	100mA / 1V	150	6	3 1
	BC847A	NPN	45	100	110~230	2mA / 5V	200	3	3.
	BC847B	NPN	45	100	200~450	2mA / 5V	200	3	31
	BC847C	NPN	45	100	450~800	2mA / 5V	200	3	310
	BC848A	NPN	30	100	110~230	2mA / 5V	200	3	Gil
	BC848B	NPN	30	100	200~450	2mA / 5V	200	3	G1K
	BC848C	NPN	30	100	420~800	2mA / 5V	200	3	G1L
	BC857A	PNP	45	100	110~230	2mA / 5V	250	4.5	G3E
Pre Amp	BC857B	PNP	45	100	210~480	2mA / 5V	250	4.5	G3F
	BC858A	PNP	30	100	110~250	2mA / 5V	250	4.5	G3L
	BC858B	PNP	30	100	210~480	2mA / 5V	250	4.5	GЗК
	BC858C	PNP	30	100	420~800	2mA / 5V	250	4.5	G3L
	BCW29	PNP	32	100	110~260	2mA / 5V		7	GC1
	BCW30	PNP	32	100	210~500	2mA / 5V		7	GC2
	BCW31	NPN	32	100	110~230	2mA / 5V		4	GD1
	BCW32	NPN	32	100	200~450	2mA / 5V	·	4	GD2
	BCW33	NPN	32	100	420~800	2mA / 5V		4	GD3
	BCW60A	NPN	32	200	110~230	2mA / 5V	125	4.5	GAA
	BCW60B	NPN	32	200	180~310	2mA / 5V	125	4.5	GAB
	BCW60C	NPN	32	200	260~460	2mA / 5V	125	4.5	GAC
	BCW60D	NPN	32	200	380~630	2mA / 5V	125	4.5	GAD
Low Noise Amp	BCW61A	PNP	32	200	110~230	2mA / 5V	180	5	GBA
	BCW61B	PNP	32	200	180~310	2mA / 5V	180	5	GBB
	BCW61C	PNP	32	200	250~460	2mA / 5V	180	5	GBC
	BCW61D	PNP	32	200	380~630	2mA / 5V	180	5	GBD
	BCW65A	NPN	32	800	100~250	100mA / 1V	100	12	GEA
	BCW65B	NPN	32	800	160~400	100mA / 1V	100	12	GEB
Driver	BCW65C	NPN	45	800	250~630	100mA / 1V	100	12	GEC
	BCW68F	PNP	45	800	100~250	100mA/ 1V	100	18	GDF
	BCW68G	PNP	45	800	160~400	100mA / 1V	100	18	GDG
	BCW69	PNP	45	100	110~260	2mA / 5V		7	GH1
	BCW70	PNP	45	100	210~500	2mA / 5V		7	GH2
Low Noise Amp	BCW71	NPN	45	100	110~230	2mA / 5V		4	GK1
	BCW72	NPN	45	100	200~450	2mA / 5V		4	GK2
	BCX17	PNP	45	500	100~600	100mA / 1V			GT1
	BCX18	PNP	25	500	100~600	100mA / 1V		1	GT2
Driver	BCX19	NPN	45	500	100~600	100mA / 1V			GU1
	BCX20	NPN	25	500	100~600	100mA / 1V			GU2
	BCX70G	NPN	45	200	110~220	2mA / 5V	125	4.5	GAG
	ВСХ7ОН	NPN	45	200	180~310	2mA / 5V	125	4.5	GAH
	BCX70J	NPN	45	200	250~460	2mA / 5V	125	4.5	GAJ
Low Noise Amp	ВСХ7ОК	NPN	45	200	380~630	2mA / 5V	125	4.5	GAK
· · · · · · · · · · · · · · · · · · ·	BCX71G	PNP	45	200	110~220	2mA / 5V	180	6	GBG
	BCX71H	PNP	45	200	140~310	2mA / 5V	180	6	GBH
	BCX71J	PNP	45	200	250~460	2mA / 5V	180	6	GBJ
Mix Osc.	BFS17	NPN	15	50	20~150	2mA / 5V	1000	1.5	GMA
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Transistors ____

SST (U.S/European SOT-23) · SMT (SC-59/Japanese SOT-23)

Packasing

Package	Packaging type	Packaging condition	Direction	Code	Quantity / Package (pcs)	Quantity / Unit (pcs)
SST	Taping En	Embossed reel tape	1 Pin side on sprocket hole side 2 Pins side on sprocket hole side	T116	3,000	_
SMT	Taping	Embossed reel taping	1 Pin side on sprocket hole side	T146	3,000	
SM1	таршу	Embossed reer taping	2 Pins side on sprocket hole side	T147	3,000	

●Packaging specifications (Unit: mm) SST · SMT Tape Reel 0.3±0.1 H .0±1.5 2.0±0 05 φ1.5 + D.1 φ178.0±2.0 φ 50. υΜιπ. Size Package Code Package Code Package В T117 T116 SST 3.15±0.1 SST SST 2.85 ± 0.1 1.4 ± 0.1 SMT T147 SMT T146 SMT 3.1 ± 0.1 3.2 ± 0.1 1.35 ± 0.1

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2N2369ADCSM 2N5769 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E
MCH4021-TL-E US6T6TR NJL0281DG 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR
EMT2T2R MCH6102-TL-E FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MHTL-E NSV40301MZ4T1G NTE101